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CLAIMS

 A process solution applying apparatus comprising:

a substrate holding mechanism for holding a
substrate;

a process solution supplying system for applying process solution in a prescribed amount to the substrate held by the substrate holding mechanism, said process solution supplying system having a supplying mechanism for changing a rate at which the process solution is supplied; and

a substrate rotating mechanism for rotating the substrate holding mechanism, thus rotating the substrate at a predetermined speed to spread the process solution by virtue of centrifugal force and to coat the substrate with the process solution.

- 2. An apparatus according to claim 1, further comprising a control device for controlling the supplying mechanism, said control device having an input section for receiving data representing the type of the resist solution and a supply speed control section for determining a rate of applying the resist solution in accordance with the type of the process solution and for driving the supplying mechanism.
- 3. An apparatus according to claim 2, wherein the rate of applying the process solution has such a value that the process solution applied in the prescribed

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amount forms a film having a uniform thickness on an entire surface of the substrate.

- 4. An apparatus according to claim 3, wherein the process solution is applied each time in an amount of 2.0 mL or less.
- 5. An apparatus according to claim 1, wherein a plurality of resist solution supplying systems are provided for supplying different types of resist solutions.
- 6. An apparatus according to claim 5, further comprising a control device for controlling the supplying mechanism, said control device having an input section for receiving data representing the type of the process solution to be applied, a selection section for selecting one of the process solution supplying systems in accordance with the type of the process solution to be applied, and a supply speed control section for determining a rate of applying the process solution through the selected process solution supplying system and for driving the supplying mechanism.
- 7. An apparatus according to claim 1, wherein said supplying mechanism has a positive-displacement pump for drawing and discharging a prescribed amount of process solution and a stepping motor for driving the positive-displacement pump and changing a rate of discharging the process solution when controlled in

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terms of rotation speed.

- 8. An apparatus according to claim 1, wherein each of the process solution supplying systems has a replaceable supply tank holding the process solution to be applied, and the supplying mechanism has a detecting section for detecting amounts of process solution remaining in the supply tanks, in accordance with operation of the process solution supplying systems.
- 9. An apparatus according to claim 1, wherein each of the process solution supplying systems has a replaceable filter through which the process solution to be applied passes, and the supplying mechanism has a detecting section for detecting the time at which the filter of each process solution supplying system is to be replaced, in accordance with operation of the process solution supplying system.
 - 10. A process solution applying method comprising: a substrate holding step of holding a substrate;
- a process solution discharging step of discharging process solution to apply the process solution to the substrate in a predetermined amount at a rate which accords with the type of the process solution, thereby to form a film having high thickness uniformity; and

a substrate rotating step for rotating the substrate at a predetermined speed, thereby to spread the process solution over the substrate by virtue of centrifugal force.

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- 11. A method according to claim 10, wherein the process solution is resist solution and applied each time in an amount of 2.0 mL or less.
- 12. A method according to claim 10, further comprising a step of controlling a rotation speed of the substrate after the process solution has been completely applied, thereby to form a film having a desired thickness.
- 13. A method according to claim 10, further comprising a step of determining the speed of discharging the process solution, in accordance with the type of the process solution.